

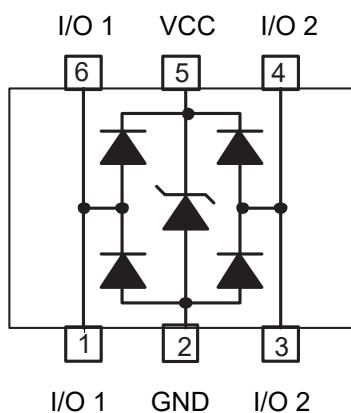
Description

The UL0552S6 is a low capacitance TVS array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The UL0552S6 has an ultra-low capacitance with a typical value at 0.4pF, and complies with the IEC 61000-4-2 (ESD) with $\pm 25\text{kV}$ air and $\pm 20\text{kV}$ contact discharge. It is assembled into a 6-pin lead-free SOT-563 package. The low capacitance array make it ideal for four high speed data and transmission line. This device is optimized for ESD protection of portable electronics.

Mechanical Characteristics

- ◆ Package: SOT-563
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

Dimensions and Pin Configuration



Circuit and Pin Schematic

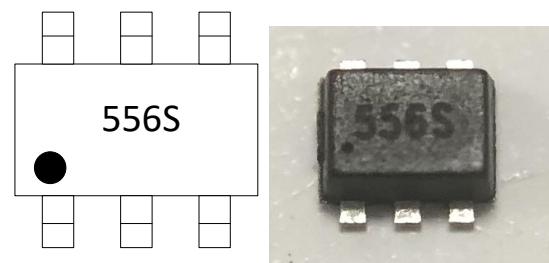
Features

- ◆ Two data lines and one power line protects
- ◆ Ultra low leakage: nA level
- ◆ Low clamping voltage
- ◆ Operating voltage: 5V
- ◆ Ultra low capacitance: 0.4pF typical(I/O to I/O)
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 25\text{kV}$
 - Contact discharge: $\pm 20\text{kV}$
 - IEC61000-4-5 (Lightning) 5A (8/20 μs)
- ◆ RoHS Compliant

Applications

- ◆ USB 2.0 Ports
- ◆ Digital Visual Interface (DVI)
- ◆ Monitor and Flat Panel Displays
- ◆ Gigabit Ethernet
- ◆ Ethernet port: 10/100Mb/s
- ◆ SIM card protection

Marking Information



556S = Device Marking Code
 Dot indicates pin1

Ordering Information

Part Number	Marking	Packaging	Reel Size
UL0552S6	556S	3000/Tape & Reel	7 inch

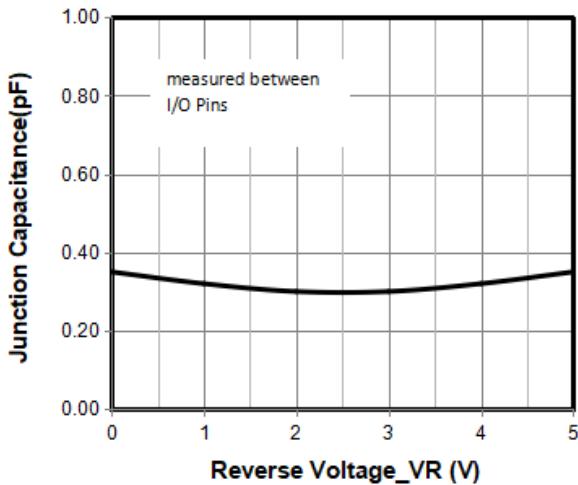
Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	75	W
Peak Pulse Current (8/20μs)	IPP	5	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±25 ±20	kV
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +125	°C

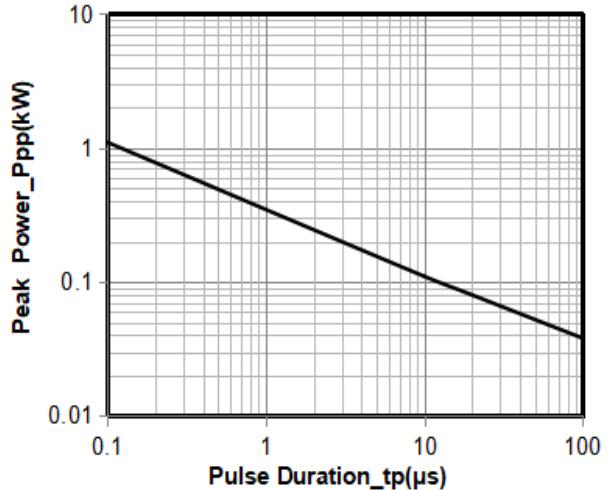
Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5	V	
Breakdown Voltage	V _{BR}	6			V	I _T = 1mA
Reverse Leakage Current	I _R			0.2	μA	V _{RWM} = 5V
Clamping Voltage	V _C			10	V	I _{PP} = 1A (8 x 20μs pulse)
Clamping Voltage	V _C			15	V	I _{PP} = 5A (8 x 20μs pulse)
Junction Capacitance	C _J		0.6	0.8	pF	VR = 0V, f = 1MHz, any I/O pin to ground
Junction Capacitance	C _J		0.3	0.4	pF	VR = 0V, f = 1MHz, between I/O pins

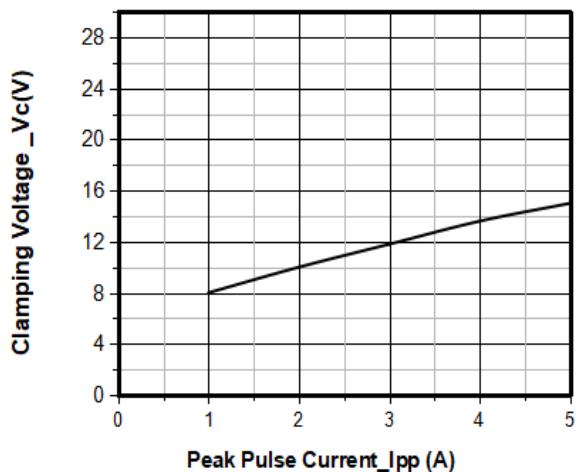
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



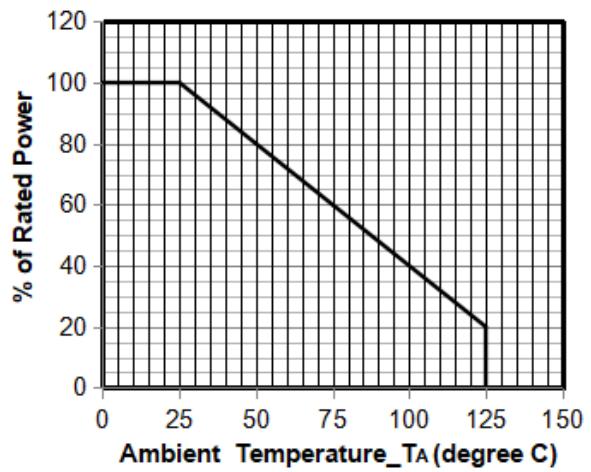
Junction Capacitance vs. Reverse Voltage



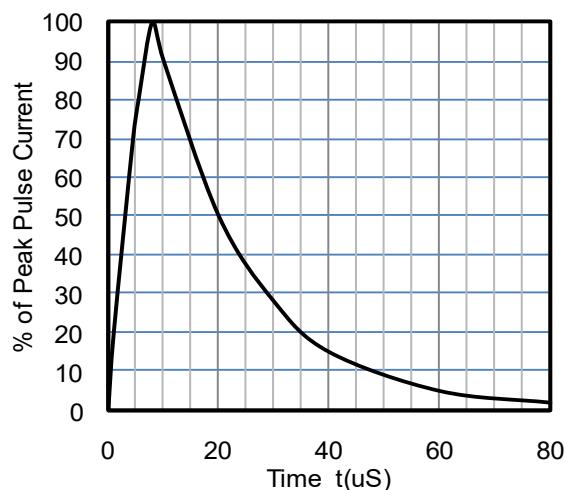
Peak Pulse Power vs. Pulse Time



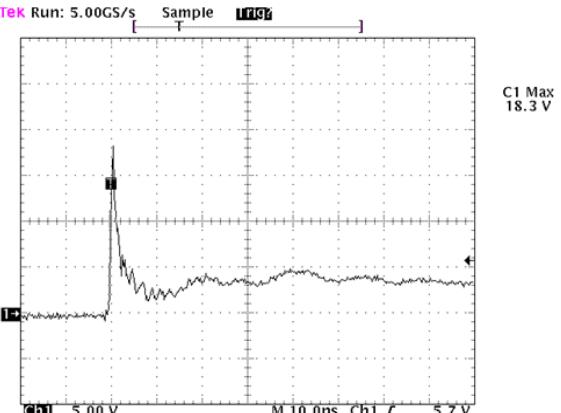
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



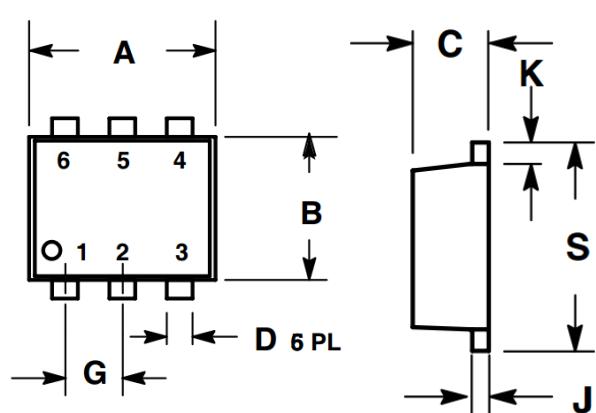
8 X 20µs Pulse Waveform



Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

SOT-563 Package Outline Drawing

SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.70	0.059	0.067
B	1.10	1.30	0.043	0.051
C	0.50	0.60	0.020	0.024
D	0.17	0.27	0.007	0.011
G	0.50 BSC		0.020 BSC	
J	0.08	0.18	0.003	0.007
K	0.10	0.30	0.004	0.012
S	1.50	1.70	0.059	0.067

Suggested Land Pattern